

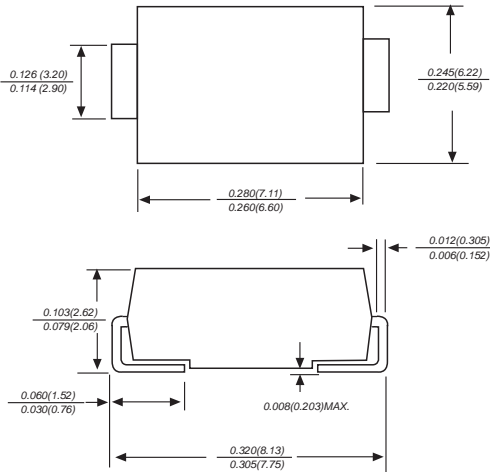


# US5A THRU US5M

## SURFACE MOUNT ULTRA FAST RECTIFIER

Reverse Voltage - 50 to 1000 Volts Forward Current - 5.0 Amperes

### DO-214AB/SMC



### FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Low reverse leakage
- ◆ Built-in strain relief, ideal for automated placement
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed: 250°C/10 seconds at terminals
- ◆ Glass passivated chip junction

### MECHANICAL DATA

**Case** : JEDEC DO-214AB molded plastic body over passivated chip  
**Terminals** : Solder plated, solderable per MIL-STD-750, Method 2026  
**Polarity** : Color band denotes cathode end  
**Mounting Position** : Any  
**Weight** : 0.007 ounce, 0.25grams

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.  
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

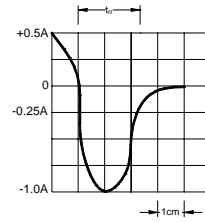
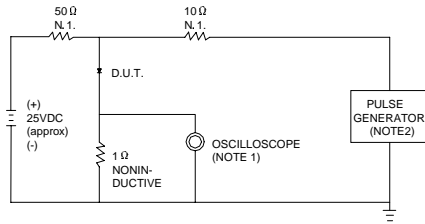
MDD Catalog Number	SYMBOLS	US5A	US5B	US5D	US5G	US5J	US5K	US5M	UNITS
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	VOLTS
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	VOLTS
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	VOLTS
Maximum average forward rectified current at $T_L=55^\circ\text{C}$	$I_{AV}$	5.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	100.0							Amps
Maximum instantaneous forward voltage at 5.0A	$V_F$	1.0		1.4		1.7		Volts	
Maximum DC reverse current at rated DC blocking voltage $T_A=25^\circ\text{C}$	$I_R$	10.0							$\mu\text{A}$
		300.0							
Maximum reverse recovery time (NOTE 1)	$t_{rr}$	50				75			ns
Typical junction capacitance (NOTE 2)	$C_J$	15				12			pF
Typical thermal resistance (NOTE 3)	$R_{\theta JA}$	15.0							$^\circ\text{C}/\text{W}$
Operating junction and storage temperature range	$T_J, T_{STG}$	-50 to +150							$^\circ\text{C}$

**Note:** 1.Reverse recovery condition  $I_F=0.5\text{A}, I_R=1.0\text{A}, t_{rr}=0.25\text{A}$   
 2.Measured at 1MHz and applied reverse voltage of 4.0V D.C.  
 3.P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas



# RATINGS AND CHARACTERISTIC CURVES US5A THRU US5M

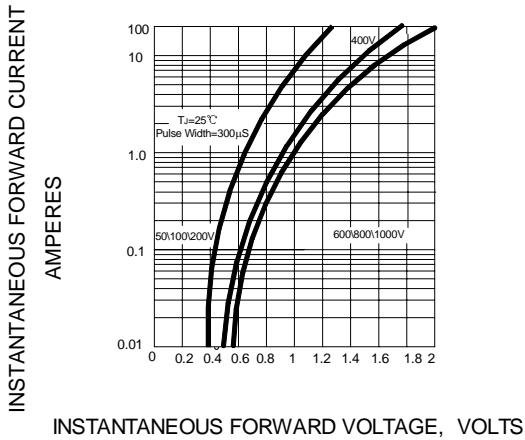
**FIG.1 – TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC**



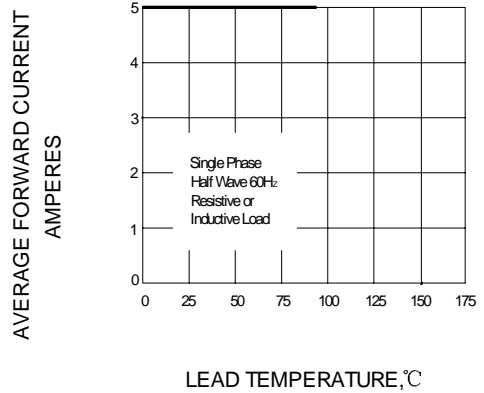
NOTES:1.RISE TIME = 7ns MAX.INPUT IMPEDANCE = 1MΩ.22pF.  
2.RISE TIME =10ns MAX.SOURCE IMPEDANCE=50 Ω.

SET TIME BASE FOR 20/30 ns/cm

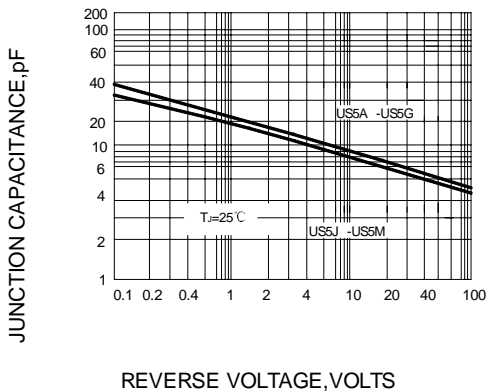
**FIG.2 – TYPICAL FORWARD CHARACTERISTIC**



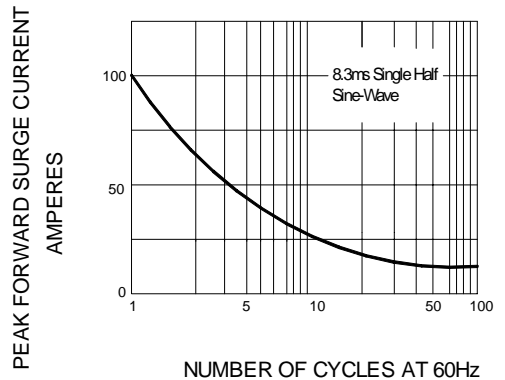
**FIG.3 – FORWARD DERATING CURVE**



**FIG.4 – TYPICAL JUNCTION CAPACITANCE**



**FIG.5 – PEAK FORWARD SURGE CURRENT**



The cruve graph is for reference only, can't be the basis for judgment(曲线图仅供参考)!



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